



# PJSD03TS~PJSD36TS

## SINGLE LINE TVS DIODE FOR ESD PROTECTION PORTABLE ELECTRONICS

**VOLTAGE** 3~36 Volts **POWER** 120 Watts

SOD-523

Unit: inch ( mm )

### FEATURES

- 120 Watts peak pulses power( tp=8/20μs)
- Small package for use in portable electronics
- Suitable replacement for MLV'S in ESD protection applications
- Low clamping voltage and leakage current
- In compliance with EU RoHS 2002/95/EC directives

### APPLICATIONS

- Case: SOD-523 plastic
- Terminals : Solderable per MIL-STD-750,Method 2026
- Approx Weight: 0.0014 grams
- Marking : PJSD03TS : KD

PJSD05TS : KE

PJSD07TS : KF

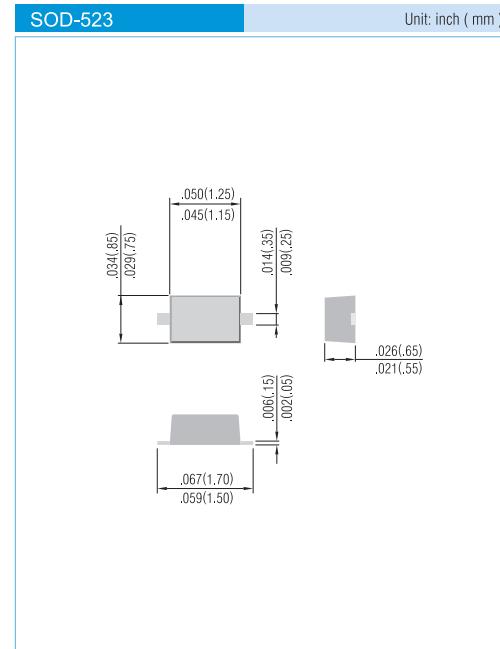
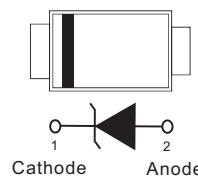
PJSD08TS : KR

PJSD12TS : LE

PJSD15TS : LM

PJSD24TS : LZ

PJSD36TS : MP



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

#### ABSOLUTE MAXIMUM RATING

Rating	Symbol	Value	Units
Peak Pulse Power Dissipation (tp=8/20 μs)	P <sub>PP</sub>	120	W
ESD Voltage	V <sub>ESD</sub>	25	kV
Operating Temperature	T <sub>J</sub>	-50 to +150	°C
Storage Temperature	T <sub>STG</sub>	-50 to +150	°C

### ELECTRICAL CHARACTERISTICS

PJSD03TS						
Parameter	Symbol	Conditions	Min.	Typical	Max.	Units
Reverse Stand-Off Voltage	V <sub>RWM</sub>	-	-	-	3.3	V
Reverse Breakdown Voltage	V <sub>BR</sub>	I <sub>BR</sub> =1mA	4	-	-	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>R</sub> =3.3V	-	-	200	μA
Clamping Voltage(8/20μs)	V <sub>C</sub>	I <sub>PP</sub> =5A	-	-	6.5	V
Off State Junction Capacitance	C <sub>J</sub>	0Vdc Bias=f=1MHz	-	-	200	pF
Off State Junction Capacitance	C <sub>J</sub>	3.3Vdc Bias=f=1MHz	-	-	100	pF



## PJSD03TS~PJSD36TS

PJSD05TS

Parameter	Symbol	Conditions	Min.	Typical	Max.	Units
Reverse Stand-Off Voltage	$V_{RWM}$	-	-	-	5	V
Reverse Breakdown Voltage	$V_{BR}$	$I_{BR}=1mA$	6.0	-	-	V
Reverse Leakage Current	$I_R$	$V_R=5V$	-	-	5	$\mu A$
Clamping Voltage(8/20 $\mu s$ )	$V_C$	$I_{PP}=5A$	-	-	9	V
Off State Junction Capacitance	$C_J$	0Vdc Bias=f=1MHz	-	-	110	pF
Off State Junction Capacitance	$C_J$	5Vdc Bias=f=1MHz	-	-	60	pF

PJSD07TS

Parameter	Symbol	Conditions	Min.	Typical	Max.	Units
Reverse Stand-Off Voltage	$V_{RWM}$	-	-	-	7.0	V
Reverse Breakdown Voltage	$V_{BR}$	$I_{BR}=1mA$	7.5	-	-	V
Reverse Leakage Current	$I_R$	$V_R=7V$	-	-	150	nA
Clamping Voltage(8/20 $\mu s$ )	$V_C$	$I_{PP}=8.8A$	-	-	22.7	V
Off State Junction Capacitance	$C_J$	0Vdc Bias=f=1MHz	-	-	85	pF

PJSD08TS

Parameter	Symbol	Conditions	Min.	Typical	Max.	Units
Reverse Stand-Off Voltage	$V_{RWM}$	-	-	-	8	V
Reverse Breakdown Voltage	$V_{BR}$	$I_{BR}=1mA$	8.5	-	-	V
Reverse Leakage Current	$I_R$	$V_R=8V$	-	-	5	$\mu A$
Clamping Voltage(8/20 $\mu s$ )	$V_C$	$I_{PP}=5A$	-	-	13	V
Off State Junction Capacitance	$C_J$	0Vdc Bias=f=1MHz	-	-	70	pF

PJSD12TS

Parameter	Symbol	Conditions	Min.	Typical	Max.	Units
Reverse Stand-Off Voltage	$V_{RWM}$	-	-	-	12	V
Reverse Breakdown Voltage	$V_{BR}$	$I_{BR}=1mA$	13.3	-	-	V
Reverse Leakage Current	$I_R$	$V_R=12V$	-	-	5	$\mu A$
Clamping Voltage(8/20 $\mu s$ )	$V_C$	$I_{PP}=5A$	-	-	17	V
Off State Junction Capacitance	$C_J$	0Vdc Bias=f=1MHz	-	-	60	pF



## PJSD03TS~PJSD36TS

PJSD15TS

Parameter	Symbol	Conditions	Min.	Typical	Max.	Units
Reverse Stand-Off Voltage	$V_{RWM}$	-	-	-	15	V
Reverse Breakdown Voltage	$V_{BR}$	$I_{BR}=1mA$	16.6	-	-	V
Reverse Leakage Current	$I_R$	$V_R=15V$	-	-	5	$\mu A$
Clamping Voltage(8/20 $\mu s$ )	$V_C$	$I_{PP}=5A$	-	-	22	V
Off State Junction Capacitance	$C_J$	0Vdc Bias=f=1MHz	-	-	50	pF

PJSD24TS

Parameter	Symbol	Conditions	Min.	Typical	Max.	Units
Reverse Stand-Off Voltage	$V_{RWM}$	-	-	-	24	V
Reverse Breakdown Voltage	$V_{BR}$	$I_{BR}=1mA$	26.7	-	-	V
Reverse Leakage Current	$I_R$	$V_R=24V$	-	-	5	$\mu A$
Clamping Voltage(8/20 $\mu s$ )	$V_C$	$I_{PP}=3A$	-	-	32	V
Off State Junction Capacitance	$C_J$	0Vdc Bias=f=1MHz	-	-	25	pF

PJSD36TS

Parameter	Symbol	Conditions	Min.	Typical	Max.	Units
Reverse Stand-Off Voltage	$V_{RWM}$	-	-	-	36	V
Reverse Breakdown Voltage	$V_{BR}$	$I_{BR}=1mA$	40	-	-	V
Reverse Leakage Current	$I_R$	$V_R=36V$	-	-	5	$\mu A$
Clamping Voltage(8/20 $\mu s$ )	$V_C$	$I_{PP}=1A$	-	-	55	V
Off State Junction Capacitance	$C_J$	0Vdc Bias=f=1MHz	-	-	20	pF



## PJSD03TS~PJSD36TS

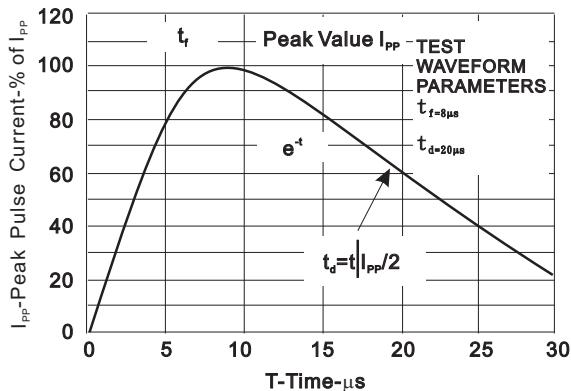


FIG. 1- Pulse Wave Form

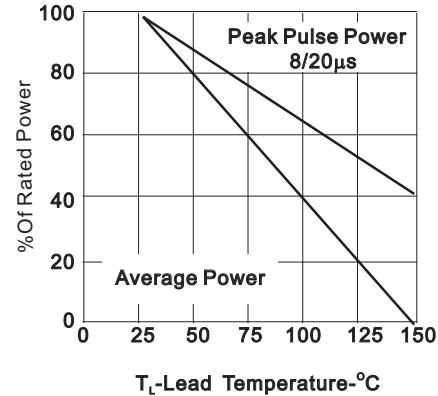


FIG. 2-Power Derating Curve

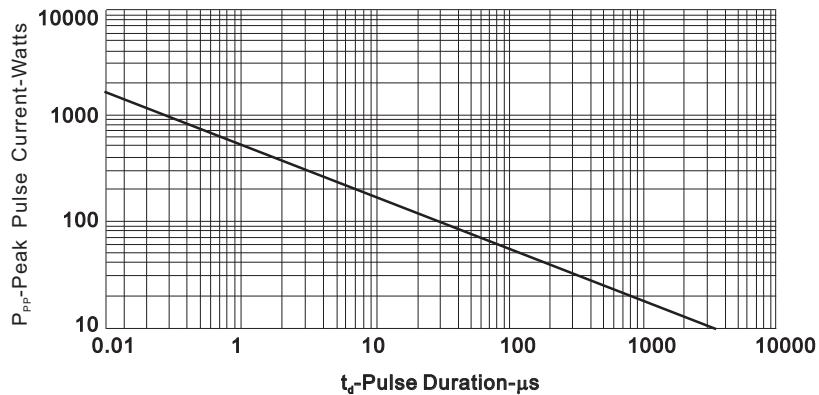
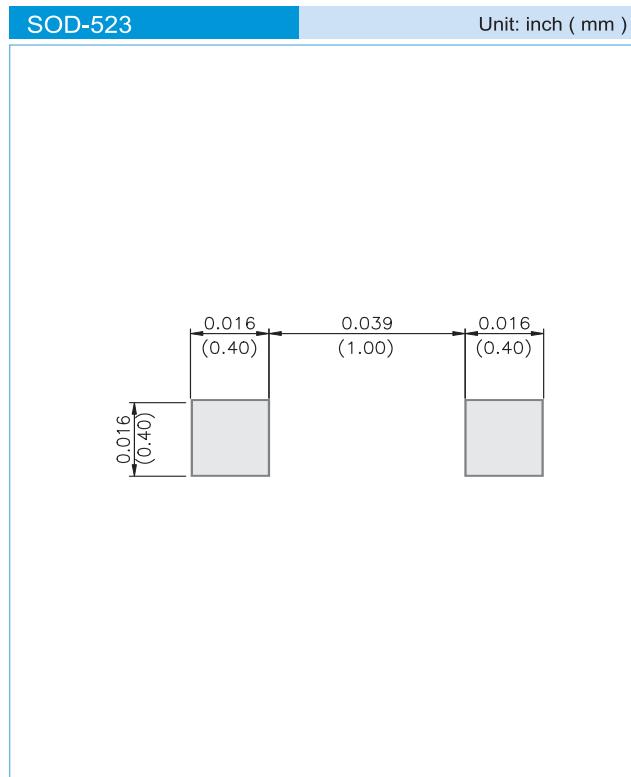


FIG. 3-Peak Pulse Power vs Pulse Time



# PJSD03TS~PJSD36TS

## MOUNTING PAD LAYOUT



## ORDER INFORMATION

- Packing information  
T/R - 12K per 13" plastic Reel  
T/R - 5K per 7" plastic Reel

## LEGAL STATEMENT

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